HEF4052B

Dual 4-channel analog multiplexer/demultiplexer Rev. 9 — 11 September 2014 Pro

Product data sheet

General description 1.

The HEF4052B is a dual 4-channel analog multiplexer/demultiplexer with common channel select logic. Each multiplexer/demultiplexer has four independent inputs/outputs (nY0 to nY3) and a common input/output (nZ). The common channel select logic includes two select inputs (S1 and S2) and an active LOW enable input (E). Both multiplexers/demultiplexers contain four bidirectional analog switches, each with one side connected to an independent input/output (nY0 to nY3) and the other side connected to a common input/output (nZ). With \overline{E} LOW, one of the four switches is selected (low-impedance ON-state) by S1 and S2. With E HIGH, all switches are in the high-impedance OFF-state, independent of S1 and S2. If break before make is needed, then it is necessary to use the enable input.

V_{DD} and V_{SS} are the supply voltage connections for the digital control inputs (S1 and S2, and E). The V_{DD} to V_{SS} range is 3 V to 15 V. The analog inputs/outputs (nY0 to nY3, and nZ) can swing between V_{DD} as a positive limit and V_{EE} as a negative limit. V_{DD} – V_{EE} may not exceed 15 V. Unused inputs must be connected to V_{DD}, V_{SS}, or another input. For operation as a digital multiplexer/demultiplexer, V_{EE} is connected to V_{SS} (typically ground). V_{EE} and V_{SS} are the supply voltage connections for the switches.

Features and benefits 2.

- Fully static operation
- 5 V, 10 V, and 15 V parametric ratings
- Standardized symmetrical output characteristics
- Specified from -40 °C to +85 °C and -40 °C to +125 °C
- Complies with JEDEC standard JESD 13-B

Applications

- Analog multiplexing and demultiplexing
- Digital multiplexing and demultiplexing
- Signal gating



Dual 4-channel analog multiplexer/demultiplexer

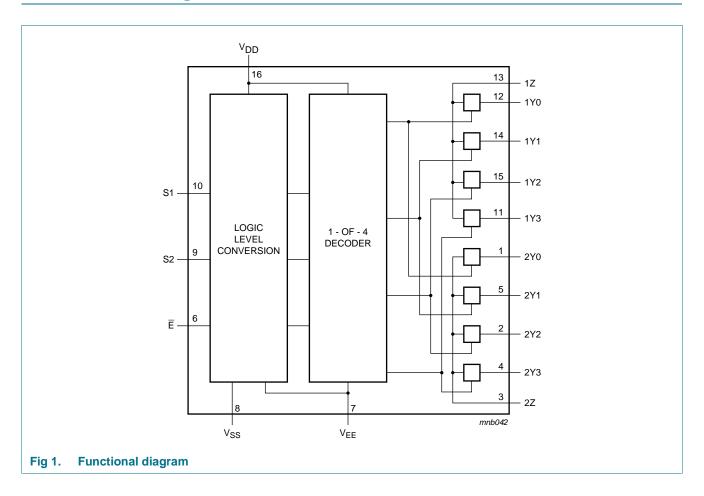
4. Ordering information

Table 1. Ordering information

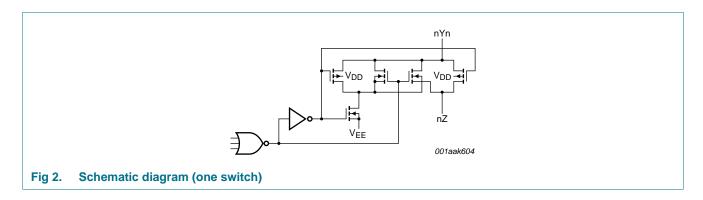
All types operate from -40~% to +125~%.

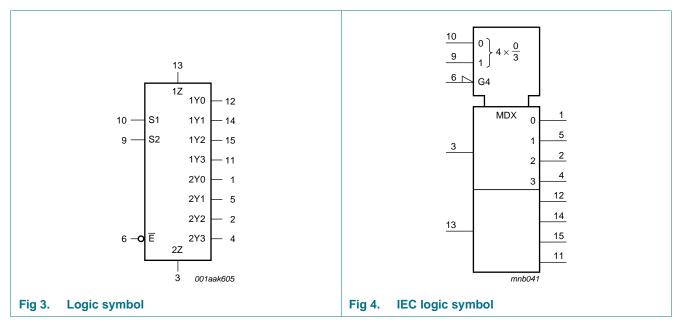
Type number	Package		
	Name	Description	Version
HEF4052BP	DIP16	plastic dual in-line package; 16 leads (300 mil)	SOT38-4
HEF4052BT	SO16	plastic small outline package; 16 leads; body width 3.9 mm	SOT109-1
HEF4052BTT	TSSOP16	plastic thin shrink small outline package; 16 leads; body width 4.4 mm	SOT403-1

5. Functional diagram

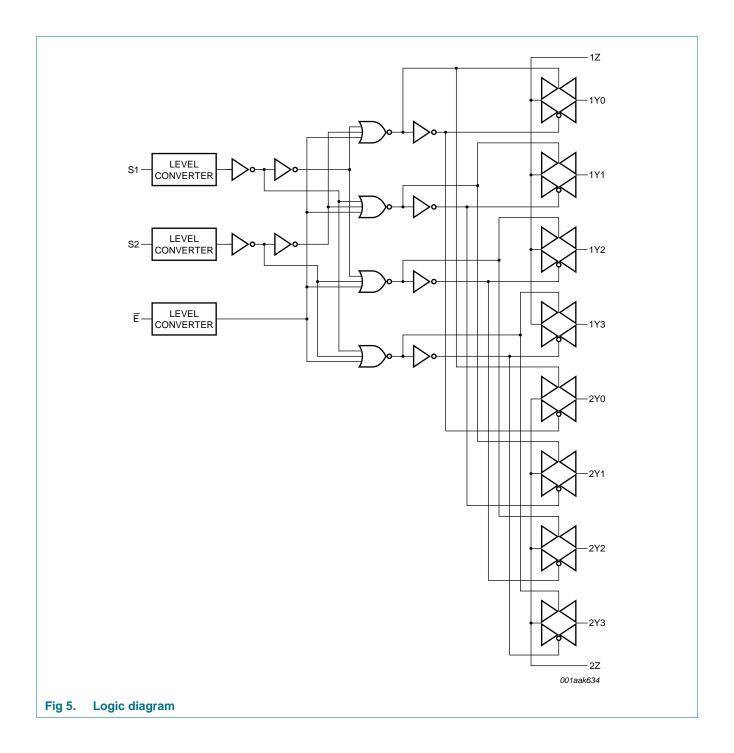


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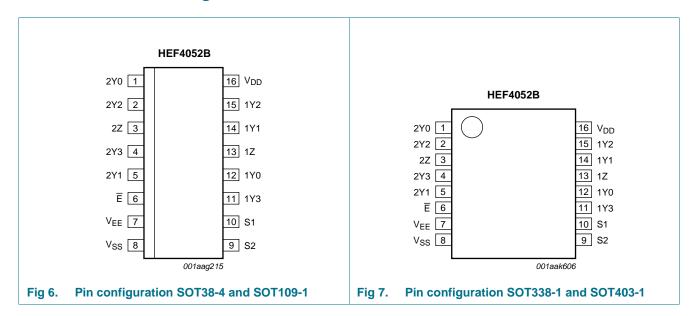
Dual 4-channel analog multiplexer/demultiplexer



Dual 4-channel analog multiplexer/demultiplexer

6. Pinning information

6.1 Pinning



6.2 Pin description

Table 2. Pin description

Symbol	Pin	Description
Ē	6	enable input (active LOW)
V _{EE}	7	supply voltage
V _{SS}	8	ground supply voltage
S1, S2	10, 9	select input
1Y0, 1Y1, 1Y2, 1Y3, 2Y0, 2Y1, 2Y2, 2Y3	12, 14, 15, 11, 1, 5, 2, 4	independent input or output
1Z, 2Z	13, 3	common output or input
V_{DD}	16	supply voltage

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7. Functional description

7.1 Function table

Table 3. Function table [1]

Input		Channel on	
E	S2	S1	
L	L	L	nY0 to nZ
L	L	Н	nY1 to nZ
L	Н	L	nY2 to nZ
L	Н	Н	nY3 to nZ
Н	X	X	switches off

^[1] H = HIGH voltage level;

L = LOW voltage level;

X = don't care.

8. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to $V_{SS} = 0 \text{ V (ground)}$.

Symbol	Parameter	Conditions		Min	Max	Unit
V_{DD}	supply voltage			-0.5	+18	V
V _{EE}	supply voltage	referenced to V _{DD}	[1]	-18	+0.5	V
I _{IK}	input clamping current	pins Sn and \overline{E} ; V _I < -0.5 V or V _I > V _{DD} + 0.5 V		-	±10	mA
VI	input voltage			-0.5	V _{DD} + 0.5	V
I _{I/O}	input/output current			-	±10	mA
I _{DD}	supply current			-	50	mA
T _{stg}	storage temperature			-65	+150	°C
T _{amb}	ambient temperature			-40	+125	°C
P _{tot}	total power dissipation	$T_{amb} = -40 ^{\circ}\text{C} \text{ to } +125 ^{\circ}\text{C}$	[2]			
		DIP16 package		-	750	mW
		SO16 package		-	500	mW
		TSSOP16 package		-	500	mW
Р	power dissipation	per output		-	100	mW

^[1] To avoid drawing V_{DD} current out of terminal Z, when switch current flows into terminals Y, the voltage drop across the bidirectional switch must not exceed 0.4 V. If the switch current flows into terminal Z, no V_{DD} current will flow out of terminals Y, and in this case there is no limit for the voltage drop across the switch, but the voltages at Y and Z may not exceed V_{DD} or V_{EE}.

[2] For DIP16 package: P_{tot} derates linearly with 12 mW/K above 70 °C.

For SO16 package: P_{tot} derates linearly with 8 mW/K above 70 $^{\circ}\text{C}.$

For SSOP16 package: P_{tot} derates linearly with 5.5 mW/K above 60 °C.

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9. Recommended operating conditions

Table 5. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{DD}	supply voltage	see Figure 8	3	-	15	V
V _I	input voltage		0	-	V_{DD}	V
T _{amb}	ambient temperature	in free air	-40	-	+125	°C
Δt/ΔV	input transition rise and fall	$V_{DD} = 5 \text{ V}$	-	-	3.75	μs/V
	rate	V _{DD} = 10 V	-	-	0.5	μs/V
		V _{DD} = 15 V	-	-	0.08	μs/V

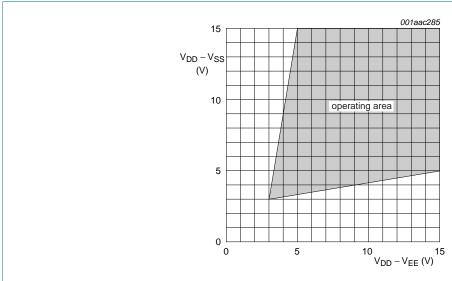


Fig 8. Operating area as a function of the supply voltages

10. Static characteristics

Table 6. Static characteristics

 $V_{SS} = V_{EE} = 0 \ V$; $V_I = V_{SS}$ or V_{DD} unless otherwise specified.

Symbol	Parameter	Conditions	V _{DD}		T _{amb} =	–40 °C	T _{amb} =	25 °C	T _{amb} =	85 °C	T _{amb} =	125 °C	Unit	
					Min	Max	Min	Max	Min	Max	Min	Max		
V_{IH}	V _{IH} HIGH-level input voltage	$ I_{O} < 1 \mu A$	5 V		3.5	-	3.5	-	3.5	-	3.5	-	V	
		input voltage		10 V		7.0	-	7.0	-	7.0	-	7.0	-	V
			15 V		11.0	-	11.0	-	11.0	-	11.0	-	V	
V_{IL}	/ _{IL} LOW-level	ut voltage	5 V		-	1.5	-	1.5	-	1.5	-	1.5	V	
	input voltage		10 V		-	3.0	-	3.0	-	3.0	-	3.0	٧	
			15 V		-	4.0	-	4.0	-	4.0	-	4.0	٧	
l ₁	input leakage current		15 V		-	±0.1	-	±0.1	-	±1.0	-	±1.0	μΑ	

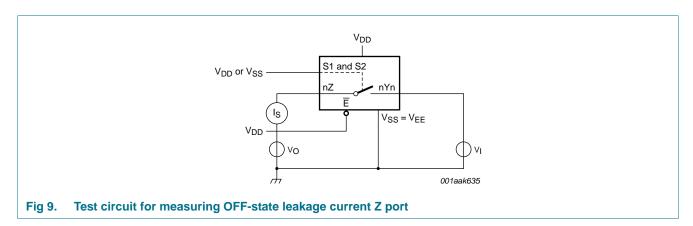
Dual 4-channel analog multiplexer/demultiplexer

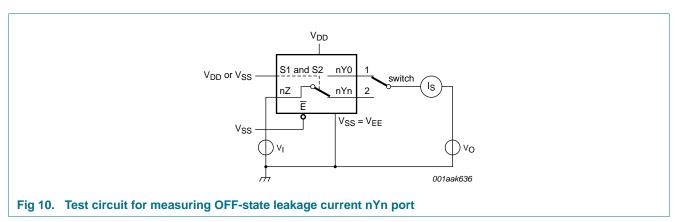
 Table 6.
 Static characteristics ...continued

 $V_{SS} = V_{EE} = 0 \ V$; $V_I = V_{SS}$ or V_{DD} unless otherwise specified.

Symbol	Parameter	Conditions	V _{DD}		T _{amb} =	–40 °C	T _{amb} =	25 °C	T _{amb} =	85 °C	T _{amb} =	125 °C	Unit
					Min	Max	Min	Max	Min	Max	Min	Max	
I _{S(OFF)}	OFF-state leakage current	Z port; all channels OFF; see <u>Figure 9</u>	15 V		-	-	-	1000	-	-	-	-	nA
		Y port; per channel; see Figure 10	15 V		-	-	-	200	-	-	-	-	nA
I _{DD}	supply current	I _O = 0 A	5 V		-	5	-	5	-	150	-	150	μΑ
			10 V		-	10	-	10	-	300	-	300	μΑ
			15 V		-	20	-	20	-	600	-	600	μΑ
Cı	input capacitance	Sn, E inputs	-		-	-	-	7.5	-	-	-	-	pF

10.1 Test circuits





Dual 4-channel analog multiplexer/demultiplexer

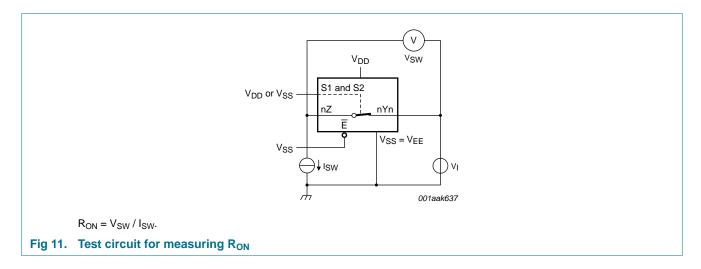
10.2 On resistance

Table 7. ON resistance

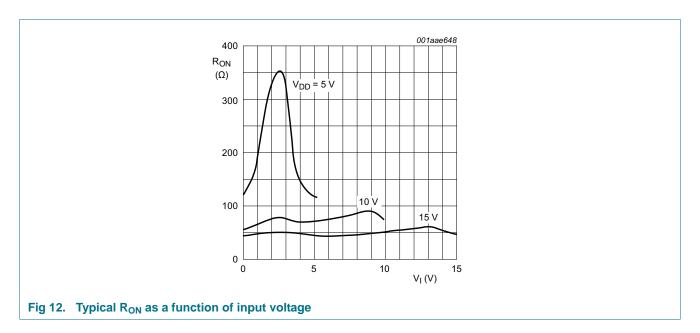
 $T_{amb} = 25$ °C; $I_{SW} = 200~\mu A$; $V_{SS} = V_{EE} = 0~V.$

Symbol	Parameter	Conditions	$V_{DD} - V_{EE}$	Тур	Max	Unit
R _{ON(peak)}	ON resistance (peak)	$V_I = 0 V \text{ to } V_{DD} - V_{EE};$	5 V	350	2500	Ω
		see Figure 11 and Figure 12	10 V	80	245	Ω
			15 V	60	175	Ω
R _{ON(rail)}	ON resistance (rail)	V _I = 0 V; see <u>Figure 11</u> and <u>Figure 12</u>	5 V	115	340	Ω
			10 V	50	160	Ω
			15 V	40	115	Ω
		$V_I = V_{DD} - V_{EE};$	5 V	120	365	Ω
		see Figure 11 and Figure 12	10 V	65	200	Ω
			15 V	50	155	Ω
ΔR_{ON}	ON resistance mismatch	$V_I = 0 \text{ V to } V_{DD} - V_{EE}$; see Figure 11	5 V	25	-	Ω
	between channels		10 V	10	-	Ω
			15 V	5	-	Ω

10.2.1 On resistance waveform and test circuit



Dual 4-channel analog multiplexer/demultiplexer



11. Dynamic characteristics

Table 8. Dynamic characteristics

 $T_{amb} = 25$ °C; $V_{SS} = V_{EE} = 0$ V; for test circuit see <u>Figure 16</u>.

Symbol	Parameter	Conditions	V_{DD}	Тур	Max	Unit
t _{PHL}	HIGH to LOW propagation delay	nYn, nZ to nZ, nYn; see Figure 13	5 V	10	20	ns
			10 V	5	10	ns
			15 V	5	10	ns
		Sn to nYn, nZ; see Figure 14	5 V	150	305	ns
			10 V	65	135	ns
			15 V	50	100	ns
t _{PLH}	LOW to HIGH propagation delay	Yn, nZ to nZ, nYn; see Figure 13	5 V	10	20	ns
			10 V	5	10	ns
			15 V	5	10	ns
		Sn to nYn, nZ; see Figure 14	5 V	150	300	ns
			10 V	75	150	ns
			15 V	50	100	ns
t _{PHZ}	HIGH to OFF-state	E to nYn, nZ; see Figure 15	5 V	95	190	ns
	propagation delay		10 V	90	180	ns
			15 V	10 20 5 10 5 10 150 300 75 150 50 100 95 190 90 180 85 180 130 260 55 115 45 85 100 205 90 180	ns	
t _{PZH}	OFF-state to HIGH	E to nYn, nZ; see Figure 15	5 V	130	260	ns
	propagation delay		10 V	55	115	ns
			15 V	45	85	ns
t _{PLZ}	LOW to OFF-state	E to nYn, nZ; see Figure 15	5 V	100	205	ns
	propagation delay		10 V	90	180	ns
			15 V	90	180	ns

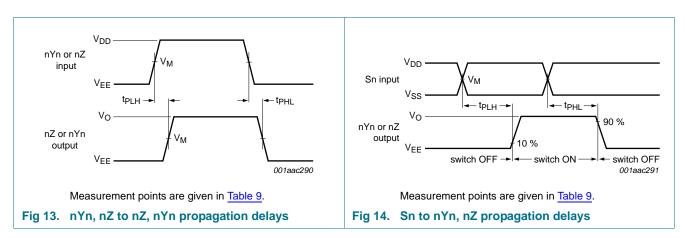
Dual 4-channel analog multiplexer/demultiplexer

 Table 8.
 Dynamic characteristics ...continued

 $T_{amb} = 25$ °C; $V_{SS} = V_{EE} = 0$ V; for test circuit see <u>Figure 16</u>.

Symbol	Parameter	Conditions	V_{DD}	Тур	Max	Unit
t _{PZL}	OFF-state to LOW	E to nYn, nZ; see Figure 15	5 V	120	240	ns
	propagation delay		10 V	50	100	ns
			15 V	35	75	ns

11.1 Waveforms and test circuit



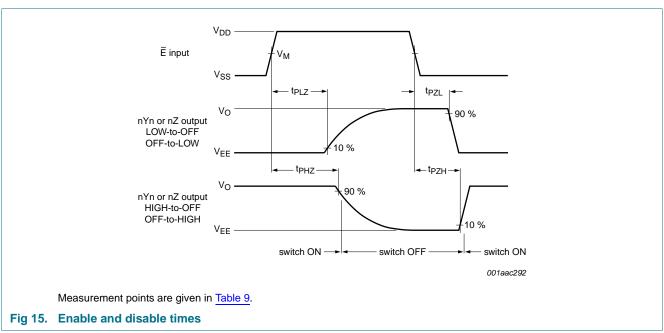
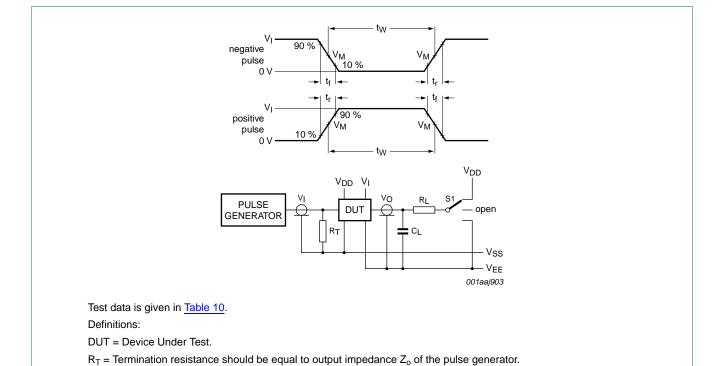


Table 9. Measurement points

Supply voltage	Input	Output
V_{DD}	V _M	V _M
5 V to 15 V	0.5V _{DD}	0.5V _{DD}

Dual 4-channel analog multiplexer/demultiplexer



 R_L = Load resistance. Fig 16. Test circuit for measuring switching times

 C_L = Load capacitance including test jig and probe.

Table 10. Test data

Input _			Load		S1 position					
nYn, nZ	Sn and E	t _r , t _f	V _M	C _L R _L		t _{PHL} [1]	t _{PLH}	t _{PZH} , t _{PHZ} t _{PZL} , t _{PLZ}		other
V_{DD} or V_{EE}	V _{DD} or V _{SS}	≤ 20 ns	0.5V _{DD}	50 pF	10 kΩ	V_{DD} or V_{EE}	V _{EE}	V _{EE}	V_{DD}	V _{EE}

[1] For nYn to nZ propagation delays use V_{EE} . For Sn to nYn or nZ propagation delays use V_{DD} .

Dual 4-channel analog multiplexer/demultiplexer

11.2 Additional dynamic parameters

Table 11. Additional dynamic characteristics

 $V_{SS} = V_{EE} = 0$ V; $T_{amb} = 25$ °C.

Symbol	Parameter	Conditions	V_{DD}		Тур	Max	Unit
THD	total harmonic distortion	see Figure 17; $R_L = 10 \text{ k}\Omega$; $C_L = 15 \text{ pF}$;	5 V	[1]	0.25	-	%
		channel ON; $V_I = 0.5V_{DD}$ (p-p); $f_i = 1 \text{ kHz}$	10 V	[1]	0.04	-	%
		II = I KIIZ	15 V	[1]	0.04	-	%
f _(-3dB)	-3 dB frequency response	see Figure 18; $R_L = 1 \text{ k}\Omega$; $C_L = 5 \text{ pF}$;	5 V	[1]	13	-	%
		channel ON; $V_I = 0.5V_{DD}$ (p-p)	10 V	[1]	40	-	MHz
			15 V	[1]	70	-	MHz
α_{iso}	isolation (OFF-state)	see Figure 19; f_i = 1 MHz; R_L = 1 k Ω ; C_L = 5 pF; channel OFF; V_I = 0.5 V_{DD} (p-p)	10 V	[1]	-50	-	dB
V _{ct}	crosstalk voltage	digital inputs to switch; see Figure 20; $\underline{R}_L = 10 \text{ k}\Omega$; $C_L = 15 \text{ pF}$; \overline{E} or $Sn = V_{DD}$ (square-wave)	10 V		50	-	mV
Xtalk	crosstalk	between switches; see Figure 21; $f_i = 1$ MHz; $R_L = 1$ k Ω ; $V_I = 0.5V_{DD}$ (p-p)	10 V	[1]	-50	-	dB

^[1] f_i is biased at 0.5 V_{DD} ; $V_I = 0.5 V_{DD}$ (p-p).

Table 12. Dynamic power dissipation P_D

 P_D can be calculated from the formulas shown; $V_{EE} = V_{SS} = 0$ V; $t_r = t_f \le 20$ ns; $T_{amb} = 25$ °C.

<i>D</i>			· / LL OO · / · · · · · · · · · · · · · · · ·	
Symbol	Parameter	V_{DD}	Typical formula for P _D (μW)	where:
P_D		5 V	$P_D = 1300 \times f_i + \Sigma (f_o \times C_L) \times V_{DD}^2$	f _i = input frequency in MHz;
dissipation		10 V	$P_D = 6100 \times f_i + \Sigma (f_0 \times C_L) \times V_{DD}^2$	fo = output frequency in MHz;
		15 V	$P_D = 15600 \times f_i + \Sigma (f_0 \times C_L) \times V_{DD}^2$	C_L = output load capacitance in pF;
				V _{DD} = supply voltage in V;
				$\Sigma(C_L \times f_o)$ = sum of the outputs.

11.2.1 Test circuits

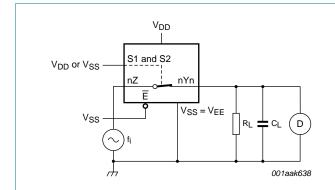


Fig 17. Test circuit for measuring total harmonic distortion

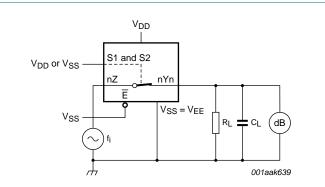
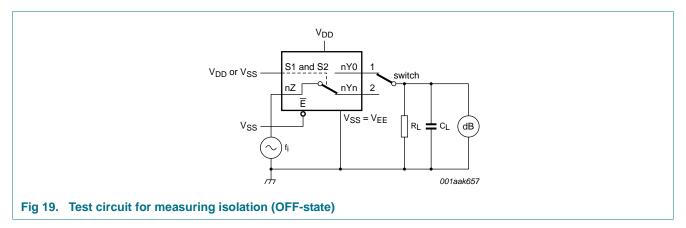


Fig 18. Test circuit for measuring frequency response

Dual 4-channel analog multiplexer/demultiplexer



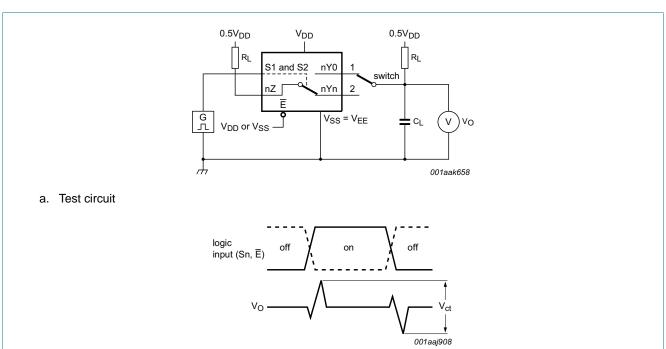
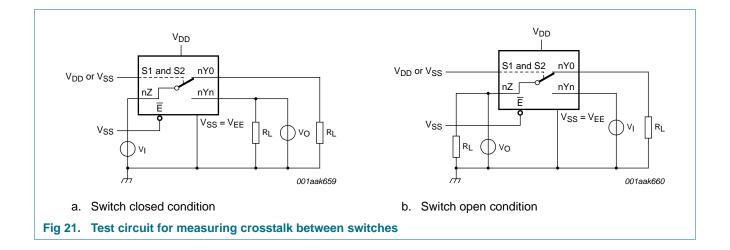


Fig 20. Test circuit for measuring crosstalk voltage between digital inputs and switch

b. Input and output pulse definitions

Dual 4-channel analog multiplexer/demultiplexer

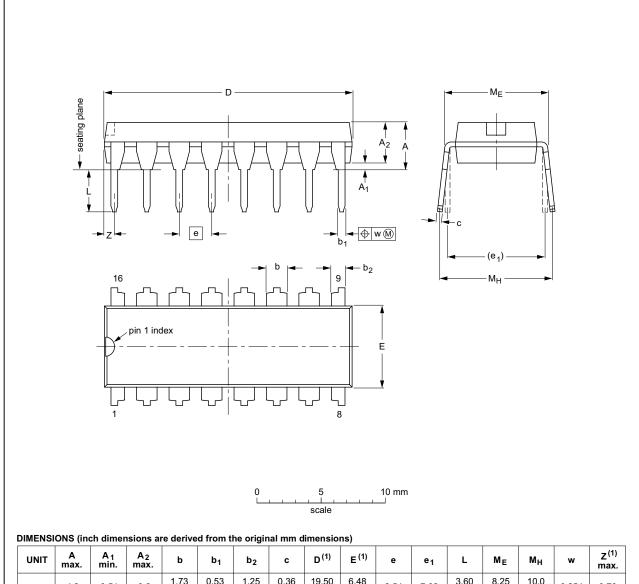


Dual 4-channel analog multiplexer/demultiplexer

12. Package outline

DIP16: plastic dual in-line package; 16 leads (300 mil)

SOT38-4



UNIT	A max.	A ₁ min.	A ₂ max.	b	b ₁	b ₂	С	D ⁽¹⁾	E ⁽¹⁾	е	e ₁	L	ME	M _H	w	Z ⁽¹⁾ max.
mm	4.2	0.51	3.2	1.73 1.30	0.53 0.38	1.25 0.85	0.36 0.23	19.50 18.55	6.48 6.20	2.54	7.62	3.60 3.05	8.25 7.80	10.0 8.3	0.254	0.76
inches	0.17	0.02	0.13	0.068 0.051	0.021 0.015	0.049 0.033	0.014 0.009	0.77 0.73	0.26 0.24	0.1	0.3	0.14 0.12	0.32 0.31	0.39 0.33	0.01	0.03

Note

1. Plastic or metal protrusions of 0.25 mm (0.01 inch) maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE	
SOT38-4						95-01-14 03-02-13	

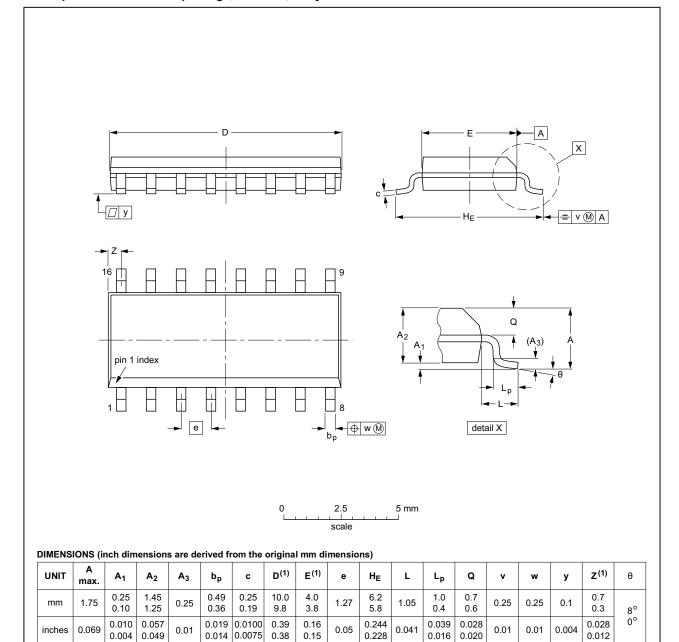
Fig 22. Package outline SOT38-4 (DIP16)

HEF4052B

Dual 4-channel analog multiplexer/demultiplexer

SO16: plastic small outline package; 16 leads; body width 3.9 mm

SOT109-1



Note

1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE	
SOT109-1	076E07	MS-012				99-12-27 03-02-19	

Fig 23. Package outline SOT109-1 (SO16)

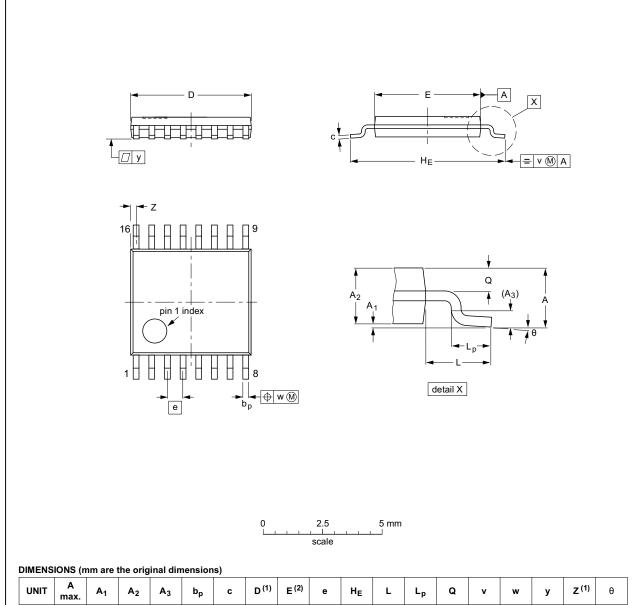
HEF4052B

HEF4052B NXP Semiconductors

Dual 4-channel analog multiplexer/demultiplexer

TSSOP16: plastic thin shrink small outline package; 16 leads; body width 4.4 mm

SOT403-1



						-,												
UNIT	A max.	A ₁	A ₂	A ₃	bp	С	D ⁽¹⁾	E ⁽²⁾	е	HE	L	Lp	Q	v	w	у	Z ⁽¹⁾	θ
mm	1.1	0.15 0.05	0.95 0.80	0.25	0.30 0.19	0.2 0.1	5.1 4.9	4.5 4.3	0.65	6.6 6.2	1	0.75 0.50	0.4 0.3	0.2	0.13	0.1	0.40 0.06	8° 0°

Notes

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

			REFERENCES						
IEC	JEDEC	JEITA	PROJECTIO		ISSUE DATE				
	MO-153				99-12-27 03-02-18				

Fig 24. Package outline SOT403-1 (TSSOP16)

Dual 4-channel analog multiplexer/demultiplexer

13. Abbreviations

Table 13. Abbreviations

Acronym	Description
DUT	Device Under Test

14. Revision history

Table 14. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes				
HEF4052B v.9	20140911	Product data sheet	-	HEF4052B v.8				
Modifications:	• <u>Figure 20</u> : T	est circuit modified						
HEF4052B v.8	20111117	Product data sheet	-	HEF4052B v.7				
Modifications:	 Legal pages 	updated.						
	 Changes in "General description", "Features and benefits" and "Applications". 							
HEF4052B v.7	20100326	Product data sheet	-	HEF4052B v.6				
HEF4052B v.6	20100308	Product data sheet	-	HEF4052B v.5				
HEF4052B v.5	20091127	Product data sheet	-	HEF4052B v.4				
HEF4052B v.4	20090924	Product data sheet	-	HEF4052B_CNV v.3				
HEF4052B_CNV v.3	19950101	Product specification	-	HEF4052B_CNV v.2				
HEF4052B_CNV v.2	19950101	Product specification	-	-				

Dual 4-channel analog multiplexer/demultiplexer

15. Legal information

15.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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Dual 4-channel analog multiplexer/demultiplexer

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Dual 4-channel analog multiplexer/demultiplexer

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